What is claimed is:

1. An active type light emitting display device in which a large number of pixel structures are arranged, said pixel structure at least comprising a light emitting element; a driving TFT driving the light emitting element so that the light emitting element emits light; a controlling TFT controlling a gate voltage of the driving TFT; a threshold voltage generating element provided between the controlling TFT and a gate of the driving TFT and generating a gate voltage given to the driving TFT by level shifting a voltage corresponding to a threshold voltage of the driving TFT; a capacitor temporarily holding the gate voltage of the driving TFT; and a reset element resetting the gate voltage held in the capacitor to a predetermined voltage, wherein a current restraining means for restraining excess current from flowing into the light emitting element via the driving TFT is operated in a reset period in which the gate voltage held in the capacitor is reset to a predetermined electrical potential via the reset element.

2. The active type light emitting display device according to claim 1, wherein the threshold voltage generating element is constructed between at least one gate and one source within at least one TFT formed in one pixel structure.

3. The active type light emitting display device according to claim 1 or 2, wherein the reset element is constructed between at least one gate and one source within at least one TFT formed in one pixel structure.

4. The active type light emitting display device according to claim 3, wherein the reset element constructed between the source and the gate of the TFT is connected to the source and the gate of the TFT functioning as the threshold voltage generating element in a mutual reverse parallel state so that the gate voltage held in the capacitor is reset to a predetermined voltage by an ON operation between the source and the gate in the reset element.

5. The active type light emitting display device according to claim 1 or 2, wherein the reset element is constructed between an anode and a cathode in a diode formed in the same pixel structure including the driving TFT and the light emitting element.

6. The active type light emitting display device according to claim 5, wherein in the reset element constructed between the anode and the cathode in the diode, said cathode and said anode are connected to the source and the gate of the TFT functioning as the threshold voltage generating element, respectively, in a parallel state, and the gate voltage held in the capacitor is reset to a predetermined voltage by an ON operation between the anode and the cathode in the diode.

7. The active type light emitting display device according to claim 1 or 2, wherein the reset element is connected between a source and a drain within at least one TFT formed in one pixel structure, and the gate voltage held in the capacitor is reset to a predetermined voltage by an ON operation between said source and said drain.

8. The active type light emitting display device according to claim 1, wherein the current restraining means is laid in a series circuit composed of the driving TFT and the light emitting element and is constituted by a switching means which performs an OFF operation in the reset period.

9. The active type light emitting display device according to claim 1, wherein the current restraining means is provided between a gate voltage holding terminal of the capacitor and the gate of the driving TFT and is constituted by a switching means which performs an OFF operation in the reset period.

10. The active type light emitting display device according to claim 1, wherein the current restraining means is constituted by a switching means which is connected in parallel to both end portions of the light emitting element and which performs an ON operation in the reset period.

11. The active type light emitting display device according to claim 1, wherein the current restraining means is constituted by a voltage switching means which decreases a driving voltage applied to an anode side of the light emitting element in the reset period.

12. The active type light emitting display device according to claim 1, wherein the current restraining means is constituted by a voltage switching means which increases a driving voltage applied to a cathode side of the light emitting element in the reset period.

13. The active type light emitting display device according to claim 1, wherein the current restraining means is

constituted in such a way that a driving voltage applied to an anode side of the light emitting element is cut off from said anode side in the reset period.

14. The active type light emitting display device according to claim 1, wherein the current restraining means is constituted in such a way that a driving voltage applied to a cathode side of the light emitting element is cut off from said cathode side in the reset period.

15. The active type light emitting display device according to claim 2, wherein at least the driving TFT and a TFT forming the threshold voltage generating element are constituted by the same channel TFTs.

16. The active type light emitting display device according to claim 1, wherein the light emitting element is constituted by an organic EL element in which an organic compound is employed in a light emitting layer.